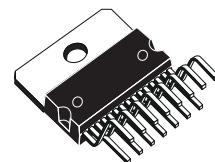


7W MONO BRIDGE AMPLIFIER

- WIDE SUPPLY VOLTAGE RANGE (3-18V)
- MINIMUM EXTERNAL COMPONENTS
 - NO SWR CAPACITOR
 - NO BOOTSTRAP
 - NO BOUCHEROT CELLS
 - INTERNALLY FIXED GAIN
- STAND-BY & MUTE FUNCTIONS
- SHORT CIRCUIT PROTECTION
- THERMAL OVERLOAD PROTECTION

TECHNOLOGY BI20II

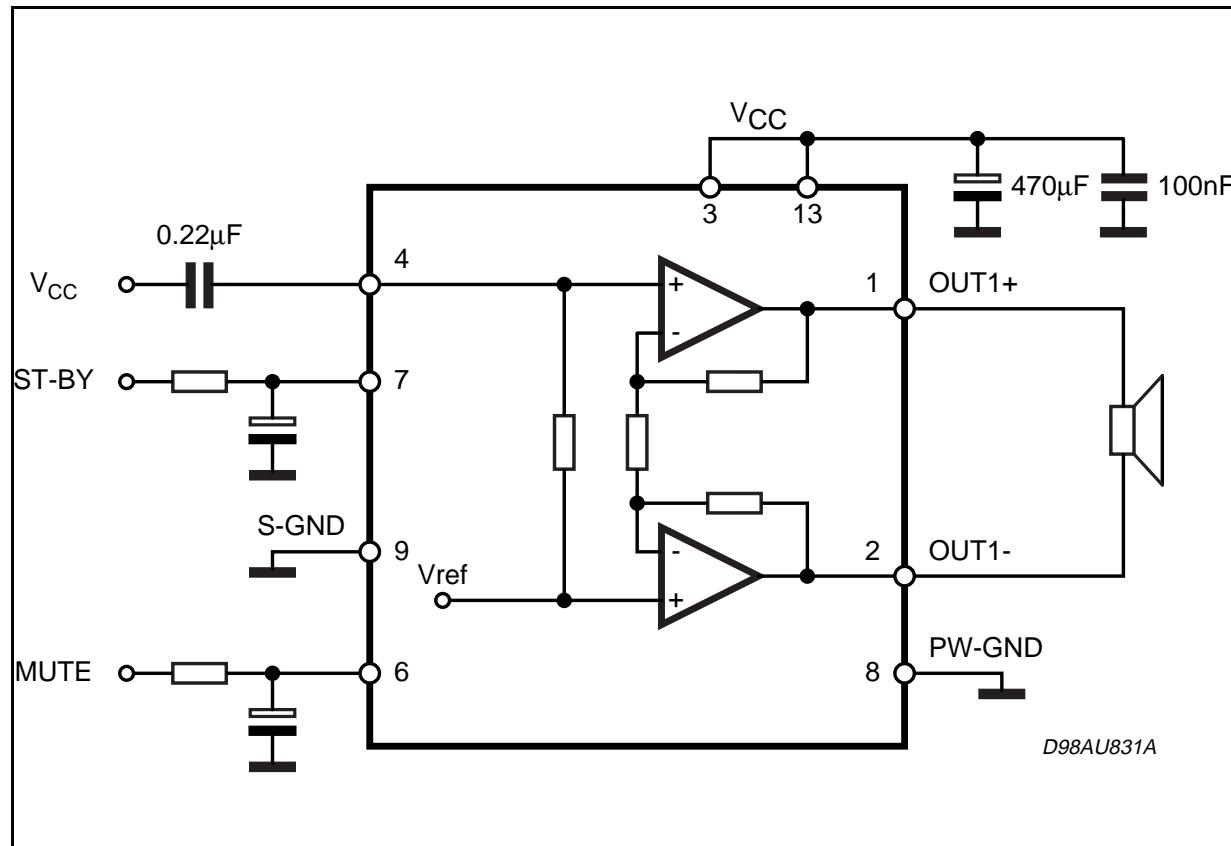


Multiwatt 15

ORDERING NUMBER: TDA7266M

DESCRIPTION

The TDA7266M is a mono bridge amplifier specially designed for TV and Portable Radio applications.

BLOCK AND APPLICATION DIAGRAM

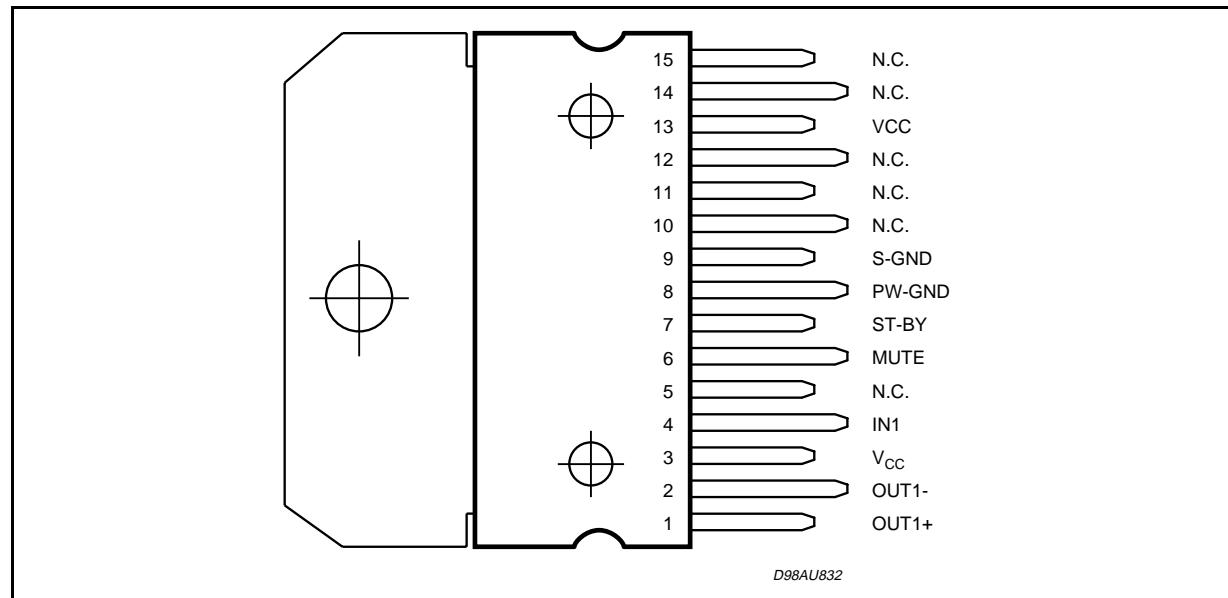
ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_S	Supply Voltage	20	V
I_O	Output Peak Current (internally limited)	2	A
P_{tot}	Total Power Dissipation ($T_{case} = 70^\circ\text{C}$)	33	W
T_{op}	Operating Temperature	0 to 70	$^\circ\text{C}$
T_{stg}, T_j	Storage and Junction Temperature	-40 to +150	$^\circ\text{C}$

THERMAL DATA

Symbol	Description	Value	Unit
$R_{thj-case}$	Thermal Resistance Junction to case	Typ. 1.4	Max. 2

PIN CONNECTION (Top view)

ELECTRICAL CHARACTERISTICS (V_{cc} = 11V, R_L = 8Ω, f = 1kHz, T_{amb} = 25°C unless otherwise specified.)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
V _{cc}	Supply Range		3	11	18	V
I _q	Total Quiescent Current			50	65	mA
V _{os}	Output Offset Voltage				120	mV
P _O	Output Power	THD = 10%	6.3	7		W
THD	Total Harmonic Distortion	P _O = 1W		0.05	0.2	%
		P _O = 0.1W to 2W f = 100Hz to 15kHz			1	%
SVR	Supply Voltage Rejection	f = 100Hz VR = 0.5V	40	56		dB
A _{MUTE}	Mute Attenuation		60	80		dB
T _w	Thermal Threshold				150	$^\circ\text{C}$
G _V	Closed Loop Voltage Gain		25	26	27	dB
R _i	Input Resistance		25	30		kΩ
V _{TMUTE}	Mute Threshold	for V _{cc} > 6.4V; V _o = -30dB for V _{cc} < 6.4V; V _o = -30dB	2.3 V _{cc} /2 -1	2.9 V _{cc} /2 -0.75	4.1 V _{cc} /2 -0.5	V V

ELECTRICAL CHARACTERISTICS (Continued)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
$V_{T_{ST-BY}}$	St-by Threshold		0.8	1.3	1.8	V
I_{ST-BY}	ST-BY current $V_6 = GND$				100	μA
e_N	Total Output Noise Voltage	A curve $f = 20Hz$ to $20kHz$		150		μV

APPLICATION SUGGESTION

STAND-BY AND MUTE FUNCTIONS

(A) Microprocessor Application

In order to avoid annoying "Pop-Noise" during Turn-On/Off transients, it is necessary to guarantee the right St-by and mute signals sequence. It's quite simple to obtain this function using a microprocessor (Fig. 1 and 2).

At first St-by signal (from μP) goes high and the voltage across the St-by terminal (Pin 7) starts to increase exponentially. The external RC network is intended to turn-on slowly the biasing circuits of

the amplifier, this to avoid "POP" and "CLICK" on the outputs.

When this voltage reaches the St-by threshold level, the amplifier is switched-on and the external capacitors in series to the input terminals (C3, C5) start to charge.

It's necessary to mantain the mute signal low until the capacitors are fully charged, this to avoid that the device goes in play mode causing a loud "Pop Noise" on the speakers.

A delay of 100-200ms between St-by and mute signals is suitable for a proper operation.

Figure 1: Microprocessor Application

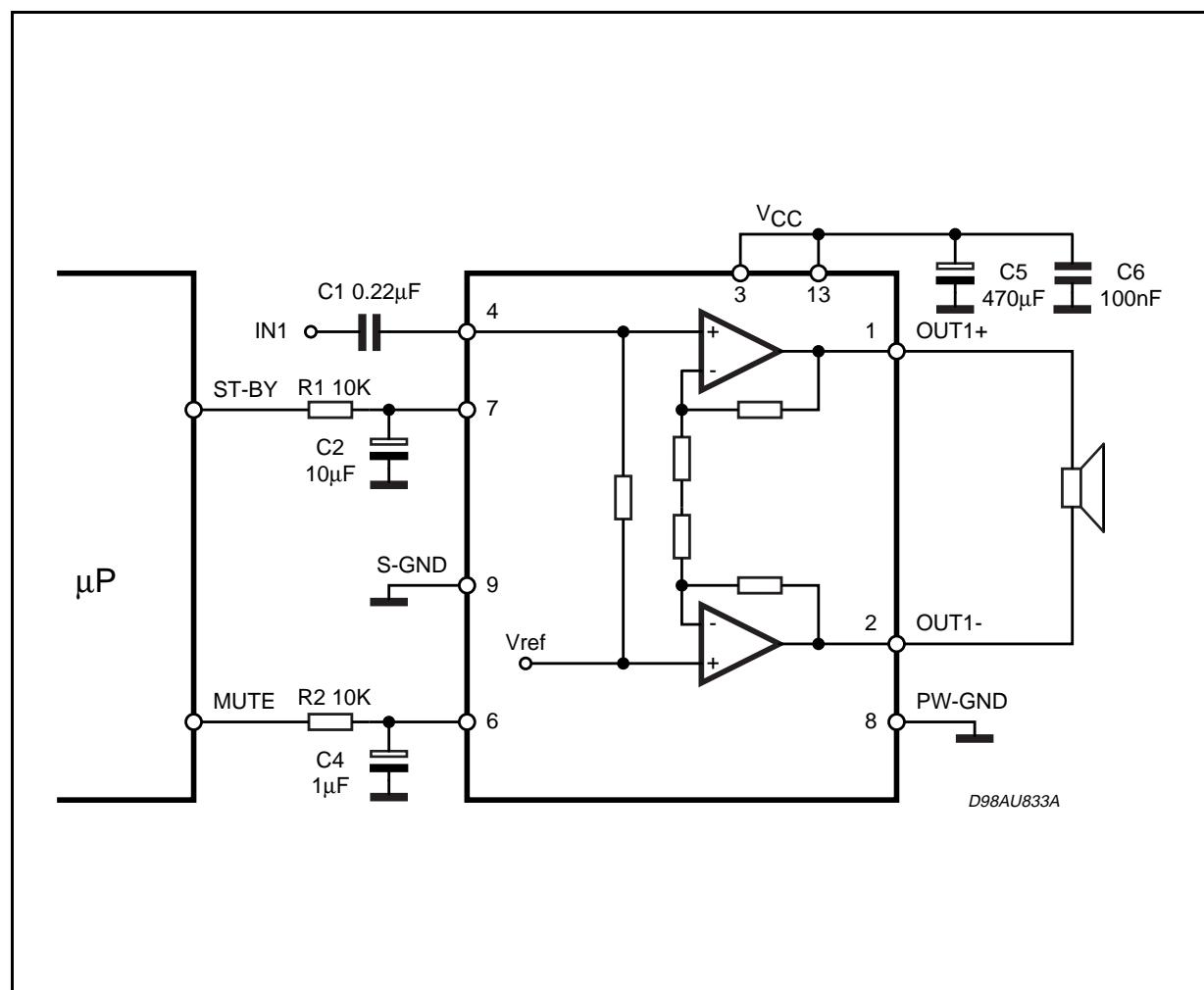
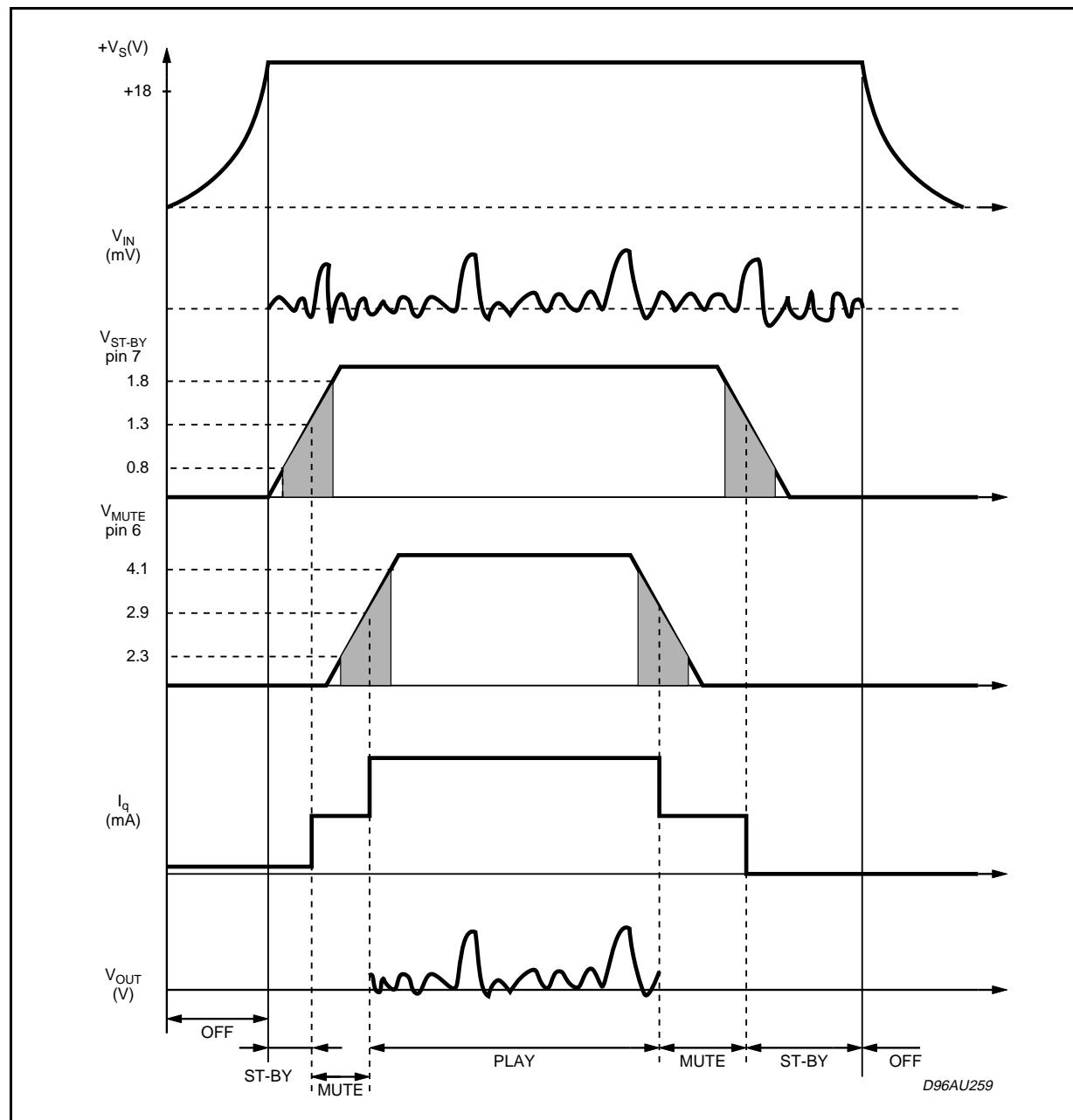


Figure 2: Microprocessor Driving Signals.

**(B) Low Cost Application**

In low cost applications where the mP is not present, the suggested circuit is shown in fig.3. The St-by and mute terminals are tied together and they are connected to the supply line via an

external voltage divider.

The device is switched-on/off from the supply line and the external capacitor C4 is intended to delay the St-by and mute threshold exceeding, avoiding "Popping" problems.

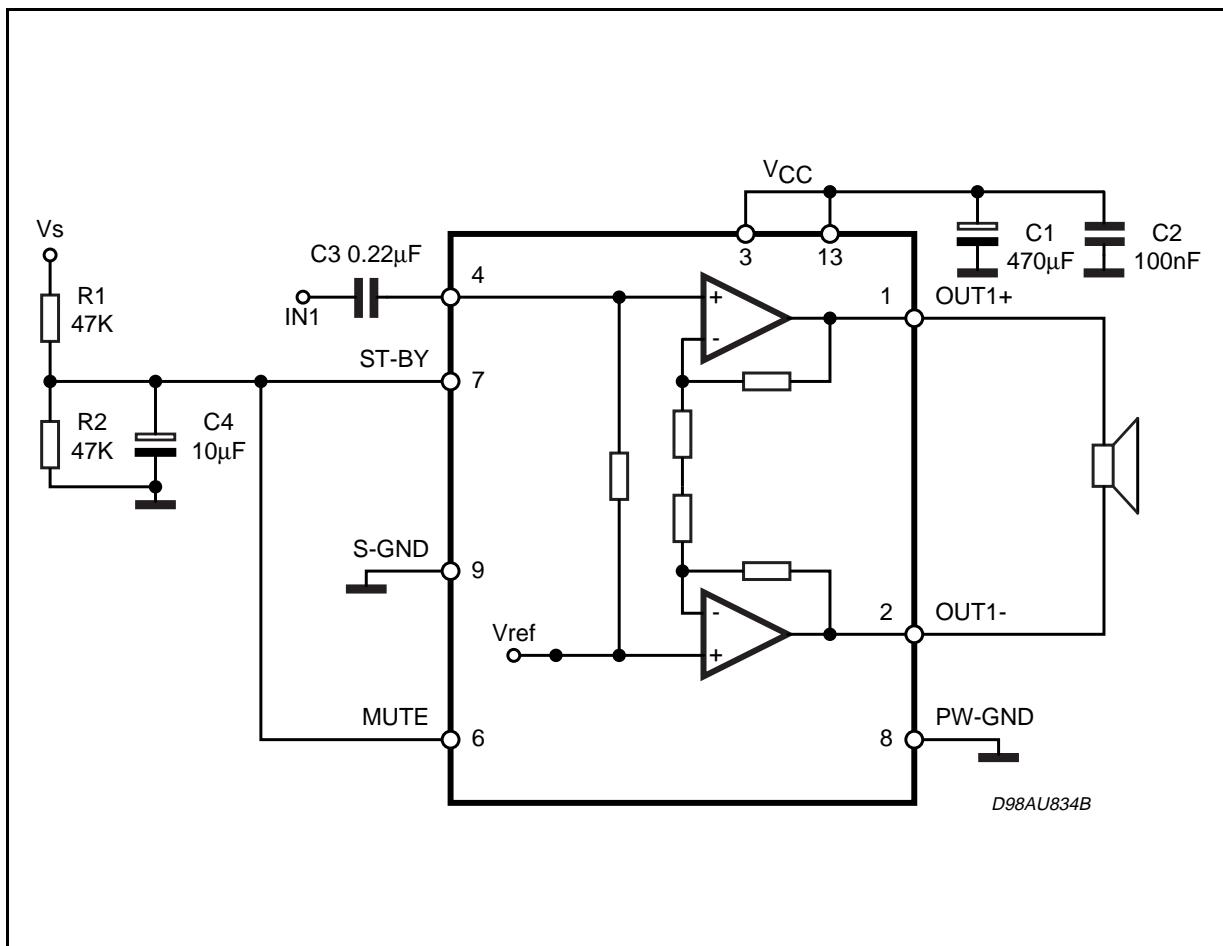
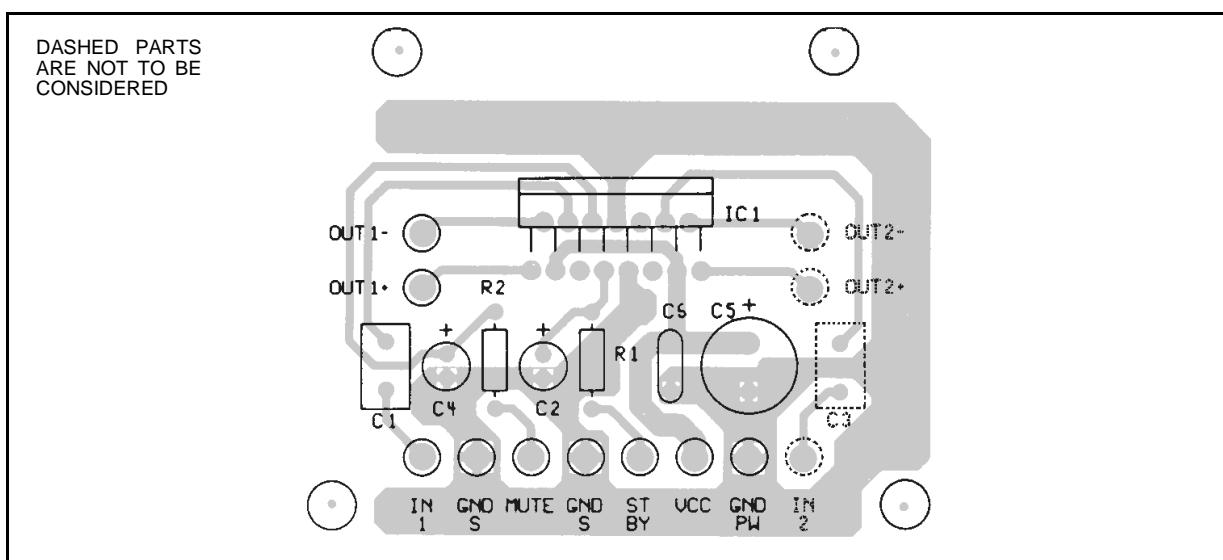
Figure 3a: Stand-alone Low-cost Application.**Figure 3b:** PCB and Component Layout of the Application Circuit (Fig. 1).

Figure 4: Distortion vs Output Power

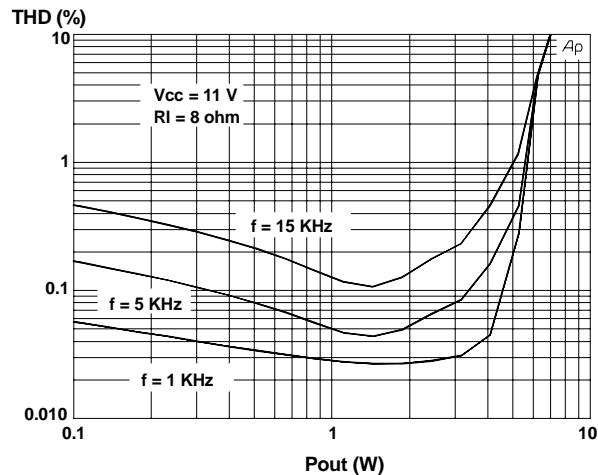


Figure 6: Distortion vs Frequency

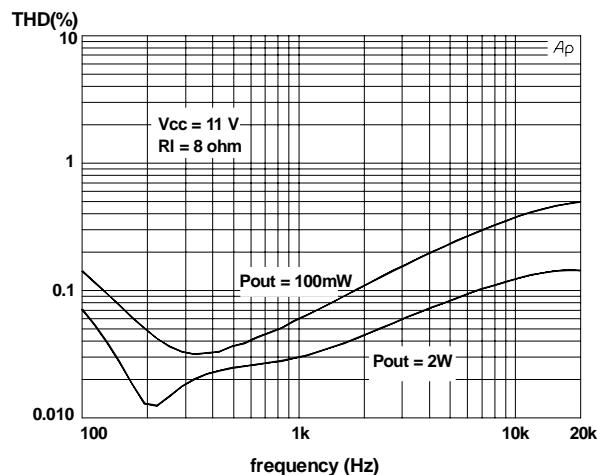


Figure 8: Output Power vs. Supply Voltage

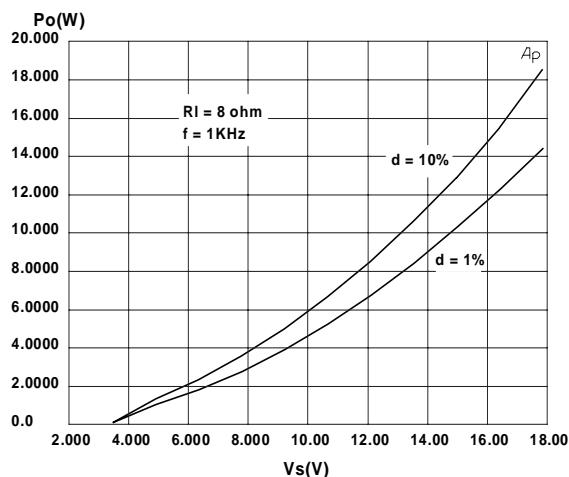


Figure 5: Distortion vs Output Power

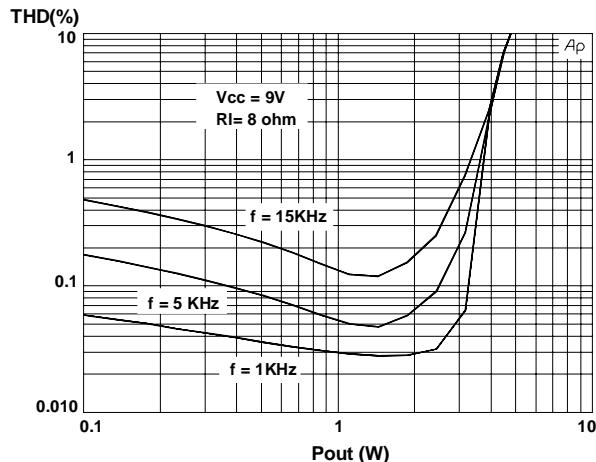


Figure 7: Gain vs Frequency

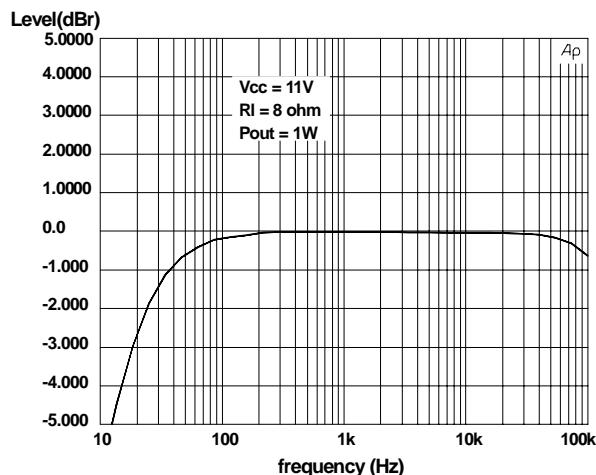


Figure 9: Total Power Dissipation & Efficiency vs. Output Power

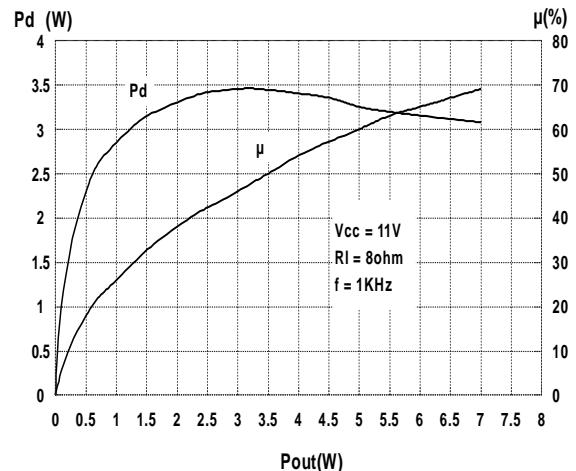
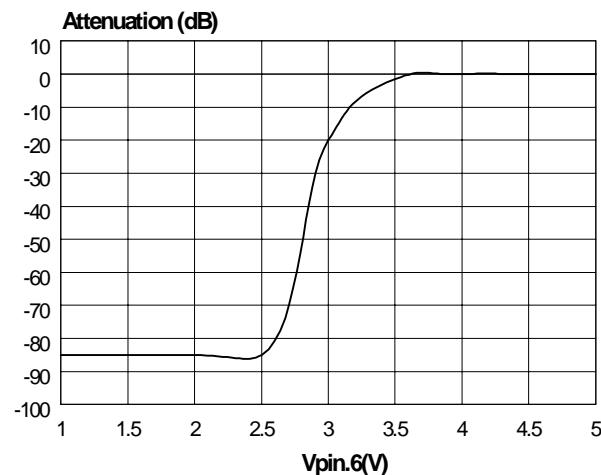
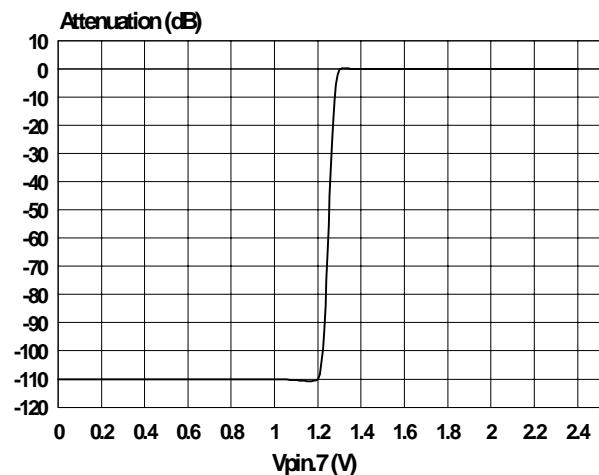
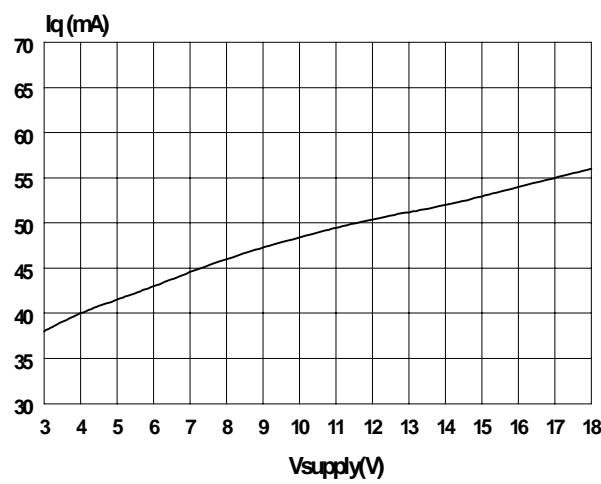
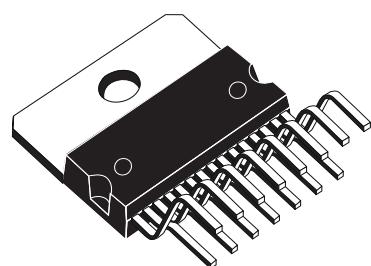


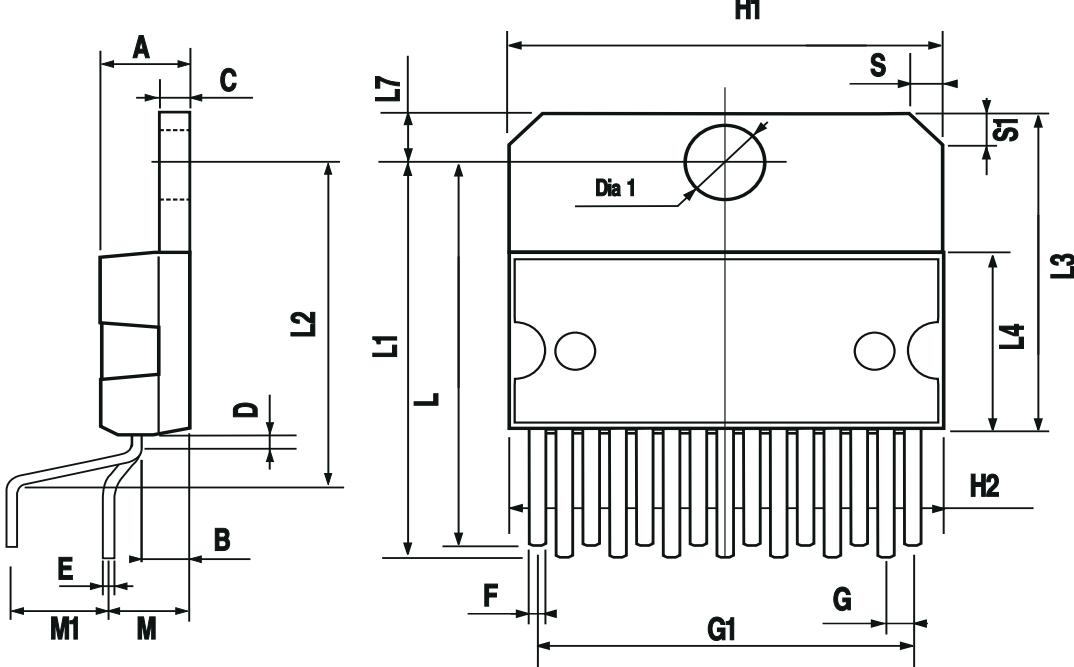
Figure 10: Mute Attenuation vs. V pin.6**Figure 11:** Stand-By Attenuation vs Vpin.7**Figure 12:** Quiescent Current vs. Supply Voltage

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			5			0.197
B			2.65			0.104
C			1.6			0.063
D		1			0.039	
E	0.49		0.55	0.019		0.022
F	0.66		0.75	0.026		0.030
G	1.02	1.27	1.52	0.040	0.050	0.060
G1	17.53	17.78	18.03	0.690	0.700	0.710
H1	19.6			0.772		
H2			20.2			0.795
L	21.9	22.2	22.5	0.862	0.874	0.886
L1	21.7	22.1	22.5	0.854	0.870	0.886
L2	17.65		18.1	0.695		0.713
L3	17.25	17.5	17.75	0.679	0.689	0.699
L4	10.3	10.7	10.9	0.406	0.421	0.429
L7	2.65		2.9	0.104		0.114
M	4.25	4.55	4.85	0.167	0.179	0.191
M1	4.63	5.08	5.53	0.182	0.200	0.218
S	1.9		2.6	0.075		0.102
S1	1.9		2.6	0.075		0.102
Dia1	3.65		3.85	0.144		0.152

OUTLINE AND MECHANICAL DATA



Multiwatt15 V



Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specification mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied. STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics

© 2002 STMicroelectronics – Printed in Italy – All Rights Reserved

STMicroelectronics GROUP OF COMPANIES

Australia - Brazil - Canada - China - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco -
Singapore - Spain - Sweden - Switzerland - United Kingdom - United States.

<http://www.st.com>



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помошь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помошь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.